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APPLICATION NO	Э.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/832,867		04/12/2001	Shunpei Yamazaki	740756-2294	1394
31780	7590	08/25/2005		EXAM	INER
ERIC RO	BINSON	ſ	LEWIS, MONICA		
PMB 955 21010 SOUTHBANK ST.				ART UNIT	PAPER NUMBER
	POTOMAC FALLS, VA 20165			2822	
			DATE MAILED: 08/25/2005		

Please find below and/or attached an Office communication concerning this application or proceeding.

		Application No.	Applicant(s)			
		09/832,867	YAMAZAKI ET AL.			
	Office Action Summary	Examiner	Art Unit			
		Monica Lewis	2822			
Period fo	The MAILING DATE of this communication r Reply	appears on the cover sheet with	the correspondence address			
THE I - Exter after - If the - If NO - Failu	ORTENED STATUTORY PERIOD FOR REMAILING DATE OF THIS COMMUNICATION IS SIX (6) MONTHS from the mailing date of this communication period for reply specified above is less than thirty (30) days, a period for reply is specified above, the maximum statutory pere to reply within the set or extended period for reply will, by signify received by the Office later than three months after the maximum adjustment. See 37 CFR 1.704(b).	DN. R 1.136(a). In no event, however, may a reply a reply within the statutory minimum of thirty (3 briod will apply and will expire SIX (6) MONTHS tatute, cause the application to become ABAN	be timely filed i0) days will be considered timely. S from the mailing date of this communication. DONED (35 U.S.C. § 133).			
Status			·			
1)🖂	Responsive to communication(s) filed on 2	77 May 2005.				
2a)⊠	This action is FINAL . 2b)	This action is non-final.				
3)	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.					
Dispositi	on of Claims	·	•			
5)⊠ 6)⊠ 7)⊠	Claim(s) <u>1-14,25-38 and 51-64</u> is/are pend 4a) Of the above claim(s) is/are with Claim(s) <u>25-38 and 51-64</u> is/are allowed. Claim(s) <u>1,2,5,6,9, 10, 13 and 14</u> is/are rej Claim(s) <u>3,4,7,8,11 and 12</u> is/are objected Claim(s) are subject to restriction ar	drawn from consideration. ected. to.				
Applicati	on Papers	•				
10)⊠	The specification is objected to by the Examine The drawing(s) filed on 12 April 2001 is/are Applicant may not request that any objection to Replacement drawing sheet(s) including the control of the oath or declaration is objected to by the	: a)⊠ accepted or b)☐ objecte the drawing(s) be held in abeyance rrection is required if the drawing(s)	s. See 37 CFR 1.85(a). is objected to. See 37 CFR 1.121(d).			
Priority L	ınder 35 U.S.C. § 119					
12)⊠ a)l	Acknowledgment is made of a claim for force All b) Some * c) None of: 1. Certified copies of the priority docum 2. Certified copies of the priority docum 3. Copies of the certified copies of the application from the International Bustee the attached detailed Office action for a	nents have been received. nents have been received in App priority documents have been re reau (PCT Rule 17.2(a)).	lication No ceived in this National Stage			
2) Notice	t(s) e of References Cited (PTO-892) e of Draftsperson's Patent Drawing Review (PTO-948 mation Disclosure Statement(s) (PTO-1449 or PTO/SE r No(s)/Mail Date <u>5/05</u> .	Paper No(s)/N	nmary (PTO-413) Mail Date rmal Patent Application (PTO-152)			

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DETAILED ACTION

1. This action is in response to the amendment filed May 27, 2005.

Specification

2. The lengthy specification has not been checked to the extent necessary to determine the presence of all possible minor errors. Applicant's cooperation is requested in correcting any errors of which applicant may become aware in the specification.

Claim Rejections - 35 USC § 102

3. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.
- 4. Claims 1, 2, 5, 6, 9, 10, 13 and 14 are rejected under 35 U.S.C. 102(e) as being anticipated by Yamazaki (U.S. Patent No. 6,501,098).

In regards to claim 1, Yamazaki discloses the following:

- a) a pixel portion having a n-channel TFT and a light emitting element over a substrate (101) (For Example: See Figure 1);
 - b) a channel forming region (104) (For Example: See Figure 1);
- c) an n-type impurity region (106a) adjacent to the channel forming region (For Example: See Figure 1);
- d) an n-type impurity region (106b) adjacent to the n-type impurity region (For Example: See Figure 1);
- e) an n-type impurity region (108) adjacent to the n-type impurity region (For Example: See Figure 1);

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- f) a gate insulating layer (103) provided over the active layer (For Example: See Figure 1);
- g) a gate electrode provided over the gate insulating layer (For Example: See Figure 1);
- h) a first conductive film (113) provided over the gate insulating layer (For Example: See Figure 1);
- i) a second conductive film (114) provided over the first conductive film, wherein the first conductive film overlaps the channel forming region and the n type impurity region with the gate insulating layer interposed therebetween, and wherein the second conductive film overlaps the channel forming region with the gate insulating layer and the first conductive film interposed between (For Example: See Figure 1); and
- j) a protection film (115) in contact with the second conductive film (For Example: See Figure 1).

In regards to claim 2, Yamazaki discloses the following:

- a) a driver circuit having a n-channel TFT over a substrate (For Example: See Column 27 Lines 23-57);
- b) pixel portion having a n-channel TFT and a light emitting element over a substrate (For Example: See Figure 1 and Figure 29);
 - c) a channel forming region (For Example: See Figure 1);
- d) an n-type impurity region adjacent to the channel forming region (For Example: See Figure 1);
- e) an n-type impurity region adjacent to the n-type impurity region (For Example: See Figure 1);
- f) an n-type impurity region adjacent to the n-type impurity region (For Example: See Figure 1);
- g) a gate insulating layer provided over the active layer (For Example: See Figure 1);
- h) a gate electrode provided over the gate insulating layer (For Example: See Figure 1);
- i) a first conductive film provided over the gate insulating layer (For Example: See Figure 1);

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j) a second conductive film provided over the first conductive film, wherein the first conductive film overlaps the channel forming region and the n type impurity region with the gate insulating layer interposed therebetween, and wherein the second conductive film overlaps the channel forming region with the gate insulating layer and the first conductive film interposed between (For Example: See Figure 1); and

k) a protection film (115) in contact with the second conductive film (For Example: See Figure 1).

In regards to claims 5 and 6, Yamazaki discloses the following:

a) the first conductive film comprises tungsten, and the second gate electrode comprises aluminum (For Example: Column 7 Lines 44-58).

In regards to claims 9 and 10, Yamazaki disclose the following:

a) the gate electrode is covered by an insulating film (123) comprising a resin film and one of a silicon nitride film and a silicon oxynitride films (For Example: See Figure 1).

In regards to claims 13 and 14, Yamazaki discloses the following:

a) the light emitting device is one selected from the group consisting of an EL display, a video camera, a digital camera, a portable computer, a personal computer, a portable telephone, and a car audio stereo (For Example: See Column 30 Lines 46-58).

Allowable Subject Matter

- 5. Claims 3, 4 and 7, 8, 11, 12 objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.
- 6. Claims 25-38 and 51-64 are allowed.

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Response to Arguments

7. Applicant's arguments filed 5/27/05 have been fully considered but they are not persuasive. First, Applicant argued that Yamazaki does not teach a protection film in contact with a second conductive film. However, Yamazaki does disclose a protection film (115) in contact with the second conductive film (114) (For Example: See Figure 1).

Second, Applicant argued that "since EP '094 has a publication date of May 31, 2000, which is later than the filing date of JP '699, the Applicant's respectfully submit that any potential rejection under 102 should be overcome." However, a rejection under 102 can still be made under Yamazaki (U.S. Patent No. 6,501,098). Subject matter developed by another person, which qualifies as prior art only under one or more subsections (e), (f), and (g) of section 102 of this title, shall not preclude patentability under this section where the subject matter and the claimed invention were, at the time the invention was made, owned by the same person or subject to an obligation of assignment to the same person. See MPEP 2146. Effective November 29, 1999, 35 U.S.C. 103(c) provides that subject matter developed by another which qualifies as "prior art" only under one or more of subsections 35 U.S.C. 102(e), (f) and (g) is not to be considered when determining whether an invention sought to be patented is obvious under 35 U.S.C. 103, provided the subject matter and the claimed invention were commonly owned at the time the invention was made. 35 U.S.C. 103(c) applies only to subject matter which qualifies as prior art under 35 U.S.C. 103; it does not affect subject matter which qualifies as prior art under 35 U.S.C. 102, i.e., anticipatory prior art. See

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MPEP § 706.02(1) - § 706.02(1)(3). Therefore, a rejection under 102 can be made under Yamazaki (U.S. Patent No. 6,501,098) since it anticipates the claimed invention.

Finally, Applicant argued that the IDS of 12/08/03 was partially considered. The Examiner did not consider the references that were crossed out on that IDS because they were not provided in the application.

Conclusion

8. THIS ACTION IS MADE FINAL. Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the mailing date of this final action.

9. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Monica Lewis whose telephone number is 571-272-1838. If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Amir Zarabian can be reached on 571-272-1852. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300 for regular and after final communications. Any inquiry of a general nature or relating to the

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status of this application or proceeding should be directed to the receptionist whose telephone number is 703-308-0956.

ML

August 22, 2005

Mary Wilczewski Primary Examiner